Revision 0.92



2020-05-25

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information

Product	Application
Tunable 760 nm DFB Laser	Oxygen Detection
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with PM Fiber and angle-polished Connector (APC)	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-40		85
Operational Temperature at Laser Chip	T_{LD}	°C	10		50
Forward Current	I _F	mA			160
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			40
TEC Current	I _{TEC}	А			1.8
TEC Voltage	V_{TEC}	V			3.2

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	-20		65
Operational Temperature at Laser Chip	T_{LD}	°C	10		35
Forward Current	I _F	mA			140
Output Power	P_{opt}	mW	10		30

Measurement Conditions / Comments
measured by integrated thermistor
ex fiber

Characteristics at T_{LD} = 25° C at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	759.9	760.9	761.9
Target Wavelength	λ_{T}	nm		760.9	
Linewidth (FWHM)	Δλ	MHz		2	
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	40		
Sidemode Supression Ratio	SMSR	dB	30	45	
Temperature Coefficient of Wavelength	$d\lambda$ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.002	

Measurement Conditions / Comments

reached within T_{LD} = 10° and 35° C at 30 mW
$P_{opt} = 30 \text{ mW}$
at target wawevelength
$P_{opt} = 30 \text{ mW}$



Revision 0.92

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Characteristics at T _{LD} = 25° C a	t BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Laser Current @ P _{opt} = 30 mW	I _{LD}	mA			150
Slope Efficiency	η	W/A		0.4	
Threshold Current	I _{th}	mA			70
Polarization Extinction Ratio	PER	dB		10	

Measurement Conditions / Comments
P _{opt} = 30 mW

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μΑ/mW	5		200
	поп орг	F			

Meası	rement Conditions / Comments
$U_R =$	5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		0.8	
Power Dissipation (total loss at case)	P _{loss}	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
$P_{opt} = 30 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 30 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 30$ mW, $\Delta T = 20$ K
$P_{opt} = 30 \text{ mW}, \Delta T = Tcase - TLD $

Thermistor ((Standard	NTC T	vne)
THORITIOLOGI	Ctariaara		y P U /

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А			1.1293 x 10	-3
Steinhart & Hart Coefficient B	В			2.3410 x 10	-4
Steinhart & Hart Coefficient C	C			8.7755 x 10	-8

Measurement Conditions / Comments		
$T_{LD} = 25^{\circ} C$		
$R_1/R_2 = e^{\beta(1/T_1-1/T_2)}$ at $T_{LD} =$	0° 50° C	
$1/T = A + B(\ln R) + C(\ln R)^3$		
T: temperature in Kelvin		
R: resistance at T in Ohm		

Ordering Information:



800 Village Walk #316 Guilford, CT 06437 Ph: 203-401-8093

Email orders to: sales@xsoptix.com Fax orders to: 800-878-7282

Revision 0.92



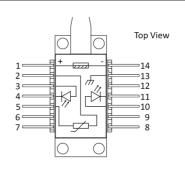
2020-05-25

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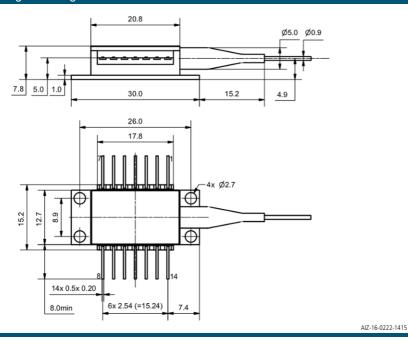


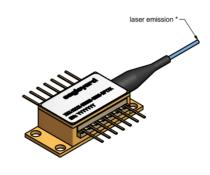
Pin Assignment

1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected



Package Drawings





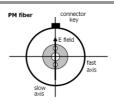
Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com

Fiber and Connector Type

PM Fiber	900 / 125 / 5.5 μ m, UV/Polyester-elastomer Coating (I = 1 +/-0.1 m)
Connector	FC/APC (narrow key / 2mm)

Measurement Conditions / Comments



Revision 0.92



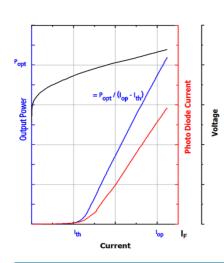
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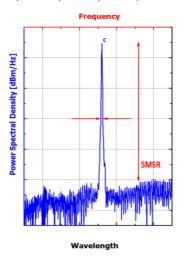


Typical Measurement Results

Output Power vs. Current



Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

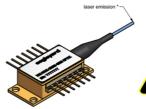
Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The DFB laser is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSURE
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 760 nm
MAX. OUTPUT POWER 40mW



